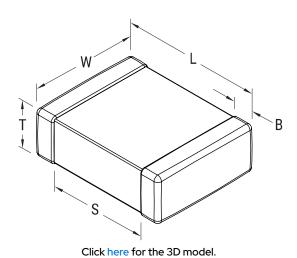


C1812F474M1RACTU

Aliases (C1812F474M1RAC7800) SMD Comm X7R FO, Ceramic, 0.47 uF, 20%, 100 VDC, X7R, SMD, MLCC, Open Mode, Temperature Stable, 1812, 2.3 mm



General Information	
Series	SMD Comm X7R FO
Style	SMD Chip
Description	SMD, MLCC, Open Mode, Temperature Stable
Features	Open Mode, Temperature Stable
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	95 mg
Shelf Life	78 Weeks
MSL	1

Dimensions	
Chip Size	1812
L	4.5mm +/-0.3mm
W	3.2mm +/-0.3mm
Т	1.1mm +/-0.10mm
S	2.3mm MIN
В	0.6mm +/-0.35mm

	1.5111111 / 0.5111111	Measurement Condition	110 12 1.0 VIIIIS
W	3.2mm +/-0.3mm	Tolerance	20%
Т	1.1mm +/-0.10mm	Voltage DC	100 VDC
S	2.3mm MIN	Dielectric Withstanding Voltage	250 VDC
В	0.6mm +/-0.35mm	Temperature Range	-55/+125°C
		Temp. Coefficient	X7R
Packaging Specifications		Capacitance Change with	15%, 1kHz 1.0Vrms
Packaging	T&R, 180mm, Plastic Tape	Reference to +25°C and 0 VDC Applied (TCC)	,
Packaging Quantity	1000	Dissipation Factor	2.5% 1 kHz 1.0Vrms
		Aging Rate	3% Loss/Decade Hour: Referee

Specifications		
Capacitance	0.47 uF	
Measurement Condition	1 kHz 1.0Vrms	
Tolerance	20%	
Voltage DC	100 VDC	
Dielectric Withstanding Voltage	250 VDC	
Temperature Range	-55/+125°C	
Temp. Coefficient	X7R	
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	15%, 1kHz 1.0Vrms	
Dissipation Factor	2.5% 1 kHz 1.0 Vrms	
Aging Rate	3% Loss/Decade Hour: Referee Time is 1000 Hours	
Insulation Resistance	2.1277 GOhms	

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

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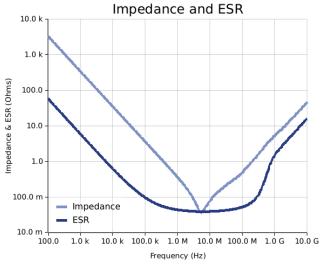


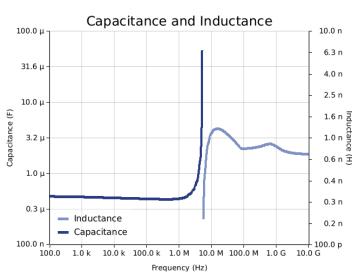
C1812F474M1RACTU

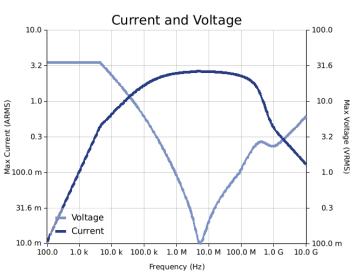
Aliases (C1812F474M1RAC7800) SMD Comm X7R FO, Ceramic, 0.47 uF, 20%, 100 VDC, X7R, SMD, MLCC, Open Mode, Temperature Stable, 1812, 2.3 mm

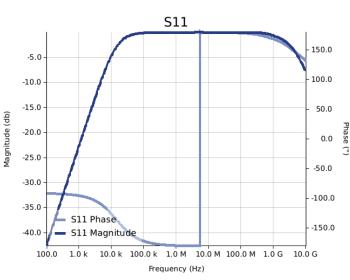
Simulations

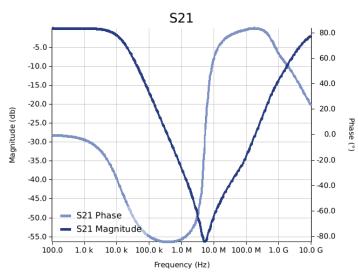
For the complete simulation environment please visit K-SIM.

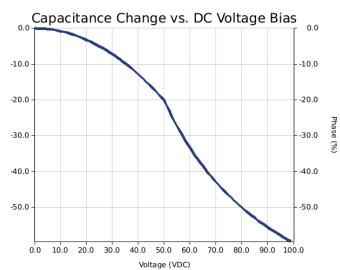












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C1812F474M1RACTU

Aliases (C1812F474M1RAC7800) SMD Comm X7R FO, Ceramic, 0.47 uF, 20%, 100 VDC, X7R, SMD, MLCC, Open Mode, Temperature Stable, 1812, 2.3 mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for ripple Ripple Currenty votage vs. rrequency plots is unleast at an interact temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.

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